

N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C	
	6mΩ @ V _{GS} = 10V		
30V	10mΩ @ V _{GS} = 4.5V	55.6A	

Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- $\bullet \qquad \text{Excellent } Q_{GD} \times R_{DS(ON)} \text{ Product (FOM)} \\$
- Advanced Technology for DC-DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% UIS (Avalanche) Rated
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

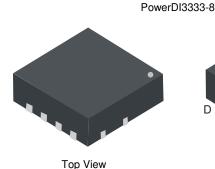
Description and Applications

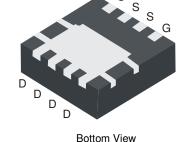
This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

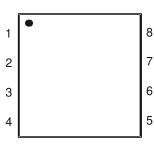
- Backlighting
- Power Management Functions
- DC-DC Converters

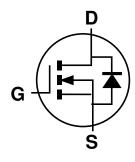
Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.072 grams (Approximate)









Top View Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMT3006LFG-7	PowerDI3333-8	2,000/Tape & Reel
DMT3006LFG-13	PowerDI3333-8	3,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



SK1 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	30	V	
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Note 6) V _{GS} = 10V	$T_C = +25$ °C $T_C = +70$ °C	I _D	55.6 44.4	Α
Continuous Drain Current (Note 5) $V_{GS} = 10V$ $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		I _D	16.0 12.8	Α
Maximum Continuous Body Diode Forward Current (Note 5)	I _S	2	Α	
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)	I _{DM}	80	Α	
Avalanche Current, L=0.1mH	I _{AS}	25	Α	
Avalanche Energy, L=0.1mH	Eas	31	mJ	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	P_{D}	27.8	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	4.5	°C/W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	54	G/VV
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}		_	1	μA	$V_{DS} = 24V$, $V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	1	_	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1.0	_	3.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance			4.8	6	mΩ	$V_{GS} = 10V, I_D = 12A$	
Static Diain-Source On-Nesistance	R _{DS(ON)}	-	6.9	10		$V_{GS} = 4.5V, I_D = 12A$	
Diode Forward Voltage	V_{SD}		0.7	1.0	V	$V_{GS} = 0V$, $I_S = 2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	1,155	_		V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	456	_	pF		
Reverse Transfer Capacitance	Crss		72	_			
Gate Resistance	R_{G}		1.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q _G	_	8.4	_			
Total Gate Charge (V _{GS} = 10V)	Q_{G}		16.7	_	nC	V _{DD} = 15V. I _D = 9A	
Gate-Source Charge	Q_{GS}	_	2.2	_	110	VDD = 13V, 1D = 9A	
Gate-Drain Charge	Q_{GD}		3.5	_			
Turn-On Delay Time	t _{D(ON)}		3.5	_			
Turn-On Rise Time	t _R		5.5	_	ns	$V_{DD} = 15V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	13.5	_	115	$R_G = 3\Omega$, $I_D = 9A$	
Turn-Off Fall Time	t _F	_	4.6				
Body Diode Reverse Recovery Time	t _{RR}	_	19.3		ns	L 1 EA di/dt 100A/us	
Body Diode Reverse Recovery Charge	Q_{RR}		8.6	_	$_{\rm nC}$ I _F = 1.5A, di/dt = 100A/ μ s		

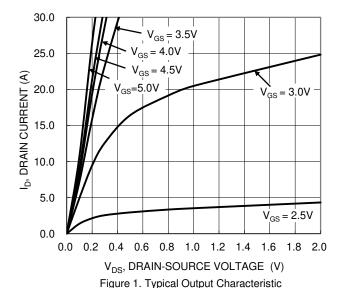
Notes: 5. R₀JA is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. R₀JC is guaranteed by design while R₀JA is determined by the user's board design.

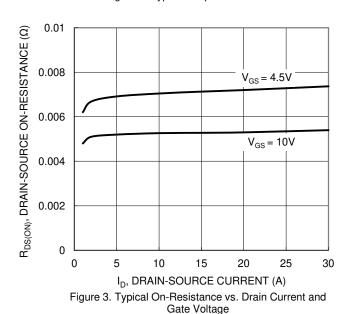
^{6.} Thermal resistance from junction to soldering point (on the exposed drain pad).

^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to product testing.







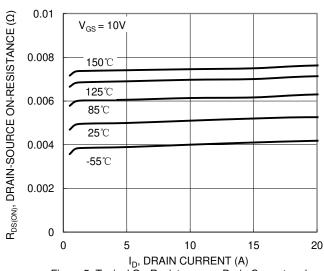
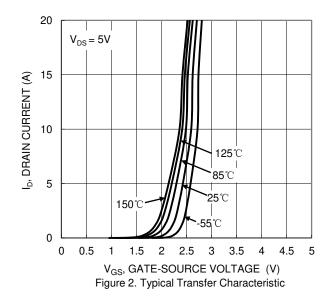
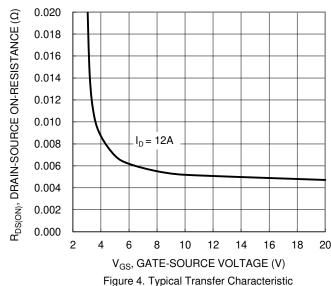


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE (NORMALIZED) 1.6 $V_{GS} = 4.5V, I_D = 12A$ 1.2 $_{GS} = 10 \text{V}, I_{D} = 12 \text{A}$ 8.0

T_.I, JUNCTION TEMPERATURE (°C) Figure 6. On-Resistance Variation with Temperature

50

75

100

25

2

0.4

-50

-25

125

150



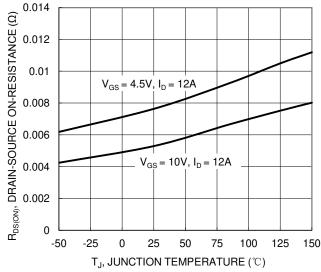
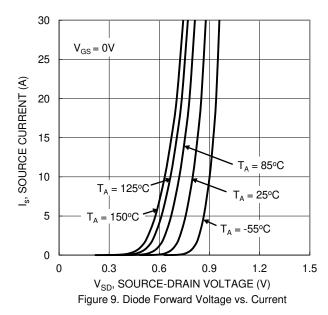


Figure 7. On-Resistance Variation with Temperature



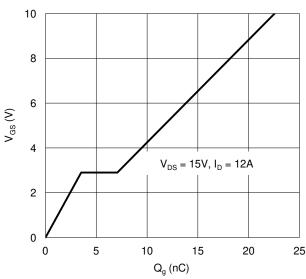


Figure 11. Gate Charge

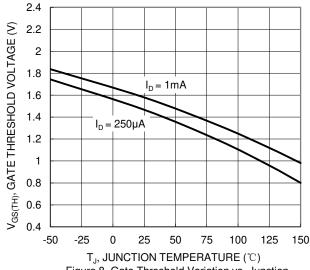
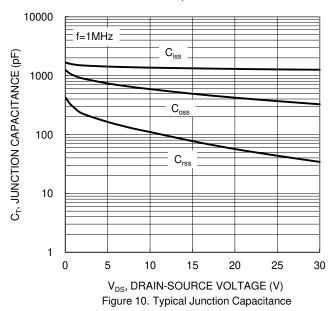


Figure 8. Gate Threshold Variation vs. Junction Temperature



100 ____ =100µs R_{DS(ON)} Limited 10 ID, DRAIN CURRENT (A) =10ms $T_{J(Max)} = 150\,{}^{\circ}\mathrm{C}$ 0.1 T_C = 25°C Single Pulse DUT on 1*MRP Board $V_{GS} = 10V$ 0.01 0.01 0.1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



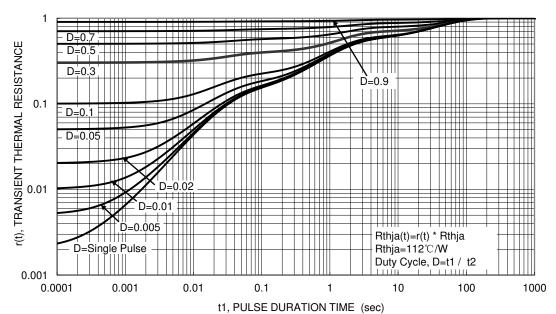


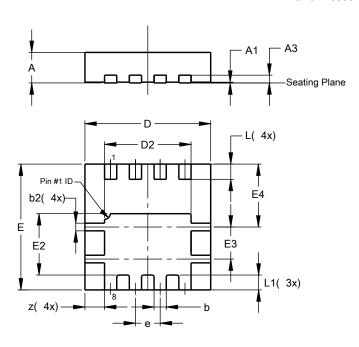
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

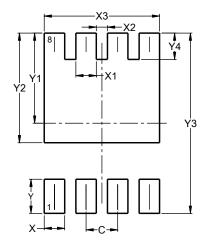


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е		_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All I	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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